Temperature Controlled Terahertz Absorbers based on Omega Resonators

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Abstract – In this article, the structural stability of a metasurface absorber that works at 2.8 THz is analyzed. Since the absorber is made of metallic titanium, its elemental inclusions will be heated up and expand when absorbing electromagnetic waves. To evaluate the accumulated heat, the structural thermal expansion and the stability of the wave-absorbing performance, electromagnetism-thermodynamics-structural mechanics multiphysics simulations are conducted. Based on the thermal stability study, thermistors are further introduced into the metasurface, leading to two thermal controlled terahertz absorbers. Numerical experiments show that the absorbers present a peak absorption coefficient of 92.7% at 2.79 THz up to the temperature of 1761.4 K. When the temperature rises, the absorption frequencies of the two absorbers shift to 3.51 THz and 3.94 THz, with the peak absorption coefficients of 92.8% and 93.8%, respectively.

Index Terms – multiphysics simulations, thermal controlled terahertz absorbers, thermal expansion.

I. INTRODUCTION

Electrically thin absorbing metasurfaces are of prime importance for many applications, for example, wave filtering \([1, 2]\), radar cross-section reduction \([3-6]\), energy harvesting \([7-10]\), phase modulating \([11, 12]\), and thermal emission control \([13-15]\). Total absorption of electromagnetic radiation requires elimination of all wave propagation channels: reflection and transmission. The electromagnetic behavior of any arbitrary scatterer may be described by its polarizability tensors \([16]\). Polarizability tensors determine the linear relation between induced dipole moments and exciting electromagnetic fields. There are various analytical and numerical approaches for calculation of polarizability tensors of scatterers \([17, 19]\). Correspondingly, electrically thin absorbers are proposed \([20]\). Among these structures, the \(\Omega\)-shaped metallic resonator is interesting because it demonstrates nearly full absorption for EM waves \([21]\). Moreover, it can be fabricated by laser lithography methods with subsequent metalization or ion beam-selective etching. So it has potential applications in spatial light modulators, sensors, bolometers and so on \([20, 22]\). However, there remain two interesting problems.

First, the absorption of electromagnetic waves is based on metallic loss which converts electromagnetic energy into thermal energy. During the process of EM wave absorbing, the heated metal structure may expand. That will affect the polarizability of the metasurface. Especially when metallic contact between the inclusions occurs, the polarizability will be changed dramatically, which would lead to a significant change in the absorbing function of the metasurface absorber. However, to the best of our knowledge, there are few studies on the thermal stability of the absorption.

Second, known from the causality principle, the maximal bandwidth of absorption of a passive absorbing layer is proportional to the layer thickness \([23, 24]\). So the full absorption of the metasurface exists only in a narrow frequency band, and the band is fixed once the structure of the metasurface is determined. Therefore, dynamically controlling the absorption band remains an interesting topic.

In this paper, we first investigated the thermal stability of a terahertz absorber based on \(\Omega\)-shaped titanium resonators. An electromagnetism-thermodynamics-structural mechanics multiphysics simulation is conducted. The simulation results show that up to the melting temperature of titanium, the absorber demonstrates stable absorption.

Second, based on the analysis of polarizability, we incorporated thermistors in the \(\Omega\) resonators and obtained temperature-controlled EM absorbers. In this
way, the absorption frequency can be shifted by controlling the temperature. Absorption coefficients of over 90% for all the bands are demonstrated in the simulations.

II. METASURFACE ABSORBING THEORY

Consider a metasurface absorber operating at 2.8 THz as proposed in [21]. The metasurface is formed with unit cells in a square lattice, with lattice constants of 37 µm. Each unit cell consists of four pairs of orthogonally arranged Ω-shaped titanium wires as shown in Fig. 1. The diameter of each Ω is 1/7 wavelength.

Fig. 1. Schematic of the array of pairs of Ω particles.

Illuminated normally by an incident plane wave, the induced electric and magnetic dipole moments \( p \) and \( m \) can be modelled with the help of polarizability [16]. Due to the subwavelength dimensions of the array elements, the dipole moments and polarizabilities can be described using the effective surface-averaged values:

\[
\begin{bmatrix}
  p \\
  m
\end{bmatrix}
= 
\begin{bmatrix}
  \alpha_{ee} & \alpha_{em} \\
  \alpha_{me} & \alpha_{mm}
\end{bmatrix}
\begin{bmatrix}
  E_{inc} \\
  \omega \times E_{inc}
\end{bmatrix},
\]

(1)

Here \( \alpha_{ee}, \alpha_{em}, \alpha_{me}, \alpha_{mm} \) are the effective electric, electromagnetic, magnetoelectric and magnetic polarizability tensors of the unit cells.

As shown in [20], the electric fields of the reflected and transmitted waves from this metasurface are given by:

\[
E_r = \frac{i\omega}{2S} \left( \eta_0 \alpha_{ee} - \frac{1}{\eta_0} \alpha_{mm} \right) E_{inc},
\]

(2)

\[
E_t = \left[ 1 + \frac{i\omega}{2S} \left( \eta_0 \alpha_{ee} + \frac{1}{\eta_0} \alpha_{mm} \right) \right] E_{inc},
\]

(3)

where \( \omega \) is the angular frequency, \( S \) is the area of the unit cell, and \( \eta_0 \) is the free-space wave impedance.

Requiring \( E_r = 0 \) and \( E_t = 0 \) in equations (2-3), one can find the conditions of symmetric total absorption in a metasurface:

\[
\eta_0 \alpha_{ee} = \frac{1}{\eta_0} \alpha_{mm} = \frac{iS}{\omega}.
\]

(4)

By introducing the normalized polarizabilities,

\[
\begin{bmatrix}
  \tilde{\alpha}_{ee} \\
  \tilde{\alpha}_{em} \\
  \tilde{\alpha}_{me} \\
  \tilde{\alpha}_{mm}
\end{bmatrix} = \frac{1}{\eta_0} \begin{bmatrix}
  \eta_0 \alpha_{ee} & \alpha_{em} \\
  \alpha_{me} & \alpha_{mm}
\end{bmatrix} = \frac{1}{\eta_0} \begin{bmatrix}
  \eta_0 \alpha_{ee} & \alpha_{em} \\
  \alpha_{me} & \frac{1}{\eta_0} \alpha_{mm}
\end{bmatrix},
\]

(5)

(4) can be transformed into a simpler form

\[
\tilde{\alpha}_{ee} = \tilde{\alpha}_{mm} = \frac{iS}{\omega}.
\]

(6)

This means the normalized electric polarizability should be equal to the normalized magnetic polarizability. Furthermore, the electric and magnetic resonance must coincide in frequency in order to demonstrate simultaneous purely imaginary electric and magnetic polarizabilities.

The thickness of the metasurface is 17 µm, which is negligible compared to structure dimensions in the xOy plane. Therefore, omitting the z-component, \( \tilde{\alpha}_{ee} \) can be expressed as:

\[
\tilde{\alpha}_{ee} = \begin{bmatrix}
  \tilde{\alpha}_{xx} & \tilde{\alpha}_{xy} \\
  \tilde{\alpha}_{yx} & \tilde{\alpha}_{yy}
\end{bmatrix},
\]

(7)

\( \tilde{\alpha}_{em}, \tilde{\alpha}_{me} \) and \( \tilde{\alpha}_{mm} \) can be expressed similarly.

III. STABILITY ANALYSIS OF THE METAMATERIAL ABSORBER

To study the thermal stability of the absorber, an electromagnetism-thermodynamics-structural mechanics multiphysics simulation was conducted by the COMSOL Multiphysics software. The radio frequency module, the heating module and the solid mechanics module were used in the simulation.

The material of the inclusions used in the unit cell (Fig. 1) is titanium, which has a conductivity of \( \sigma = 7.407 \times 10^5 \text{S/m} \), a thermal expansion coefficient of \( 7.06 \times 10^{-6} \text{1/K} \), and a melting temperature of 1941.15 K. The unit cell is surrounded by periodic boundary conditions in the x- and y-directions. In the z-direction, the PML (Perfectly Matched Layer) boundaries are applied. In the radio frequency module, a y-polarized plane wave incidence with frequency of 2.8 THz is set to impinge from the +z direction. In the heating module, the heat source is internal Joule heat. The convective heat flux is used with a heat transfer coefficient of 10 and an initial temperature of 293.15 K (room temperature). In the solid mechanics module, one end of the straight section in the Ω ring is fixed. To be specific, the bottom end for each vertical Ω ring is fixed. For each horizontal ring, the end close to the lattice boundary is fixed.

When the incident EM power is set to be \( P_{inc} = 500 \text{W/m}^2 \) and \( P_{inc} = 10000 \text{W/m}^2 \), the simulated steady-state temperature is plotted in Fig. 2.

For the y-polarized incidence, only one in each Ω pair gets heated. Further simulation shows that the other
half of the absorber gets heated with x-polarized incidence and is not plotted here. On each heated Ω-shaped inclusion, the heat distribution is uniform. For the \( P_{inc} = 500 \text{ W/m}^2 \) case, the steady temperature is 387.5 K. That temperature increases to 1761.4 K when the incident power density reaches 10000 W/m².

The corresponding expansion of the heated metamaterial absorber is plotted in Fig. 3. For each heated Ω ring, metallic expansion mainly occurs in the circular area.

![Fig. 3. Corresponding displacement in different powers, (a) in 500 W/m² and (b) in 10000 W/m².](image)

The absorption coefficient \( A \) of the absorber can be obtained from the simulated reflection coefficient \( R \) and the transmission coefficient \( T \) [21], as presented in Fig. 4. Simulations show that only when the temperature reaches 10000 K, will the Ω particles touch each other. Taking the melting temperature of titanium (1941.15 K) into account, we arrive at the conclusion that, up to the melting temperature of the material, the absorber is thermally stable.

<table>
<thead>
<tr>
<th>Temperature (K)</th>
<th>( D ) (µm)</th>
<th>( D/R ) (%)</th>
<th>Operating Frequency (THz)</th>
<th>( A ) (%)</th>
</tr>
</thead>
<tbody>
<tr>
<td>295.15</td>
<td>0</td>
<td>0</td>
<td>2.79</td>
<td>86.9</td>
</tr>
<tr>
<td>387.8</td>
<td>0.011</td>
<td>0.17</td>
<td>2.79</td>
<td>86.9</td>
</tr>
<tr>
<td>1761.4</td>
<td>0.17</td>
<td>2.58</td>
<td>2.79</td>
<td>86.9</td>
</tr>
</tbody>
</table>

IV. DESIGN AND SIMULATION RESULTS OF METASURFACE ABSORBERS

A. Design of metasurface absorbers

Based on the above thermal stability analysis, we present here the scheme to design temperature controlled metasurface absorbers by incorporating thermistors. In this scheme, the heat source may originate from the Joule heat transformed from the EM wave absorption by the Ω absorber itself, or it can be added manually through a heat conducting medium. Under this scheme, two examples are provided. As can be seen from Fig. 5 thermistors are introduced in the unit cells. In this way the functions of the metasurfaces may be dynamically controlled by temperature. Such thermistors can be realized by materials such as \( \text{VO}_2 \) [25] [26], which has an isolator phase and metallic phase with the transition temperature of around 320 K. As is shown in [25], the corresponding dynamic
range of the effective conductivity of VO$_2$ film is $10^1$-$10^5$ S/m. So for the thermistors, we used equivalent models of open circuits and short circuits at different temperatures.

![Fig. 5. Schematic of the designed absorbers, (a) Model 1, (b) Model 2, and (c) Model 3.](image)

In the first example, 8 thermistors are added to each unit cell on one side of the $\Omega$ absorber. In the second example, 16 thermistors are added to both sides of the $\Omega$ absorber, leading to a bi-directional symmetric structure. When the temperature is 295.15 K, the resistance of thermistors is much larger compared with the resistance of titanium. So in this case, the thermistors are modelled by an open circuit. Under such a temperature, the two examples have the same equivalent models (referred to as Model 1 below) as shown in Fig. 5 (a). As the temperature rises, the resistance of the thermistors decrease and hence can be modelled by a section of aluminum as plotted in green in Figs. 5 (b) (Model 2) and (c) (Model 3), respectively.

### B. Design of metasurface absorbers

From equation (6) in section II, we know that to obtain total absorption, two conditions should be satisfied. First, the normalized electric and the normalized magnetic polarizabilities of the metasurface must be equal. Second, they should be purely imaginary.

In order to validate the proposed temperature-controlled absorber designs, full-wave simulations were conducted by ANSYS High Frequency Structure Simulator (HFSS) software to evaluate the normalized polarizabilities of the proposed absorbers.

The unit cell is surrounded by periodic boundary conditions in the xOy plane, and two ports are defined in the z-direction to calculate $S$ parameters (Fig. 6). The $\Omega$ rings can be embedded in a plastic foam substrate such as polymethacrylimide (PMI) for mechanical support [27]. This PMI material is with $\varepsilon = 1.05 - 1.13$, loss tangent of $\delta = (1 - 18) \times 10^{-3}$, and thermal deformation temperature of 449-509 K.

Following the method in [18], the normalized polarizabilities $\tilde{\alpha}_{ee}$, $\tilde{\alpha}_{em}$, $\tilde{\alpha}_{me}$ and $\tilde{\alpha}_{mm}$ of Model 1 are obtained. Figure 7 shows that the entries on the diagonal of $\tilde{\alpha}_{ee}$ are of the order of $10^{-22}$. The remaining entries are of the order of $10^{-26}$. Moreover, the curves of $\tilde{\alpha}_{ee}^{xx}$ and $\tilde{\alpha}_{ee}^{yy}$ coincide. Similar results for $\tilde{\alpha}_{mm}$ can be obtained and are not plotted here. Considering the $\omega$ in equations (2) and (3) is in the order of $10^{12}$, the cross-section $S$ is in the order of $10^{-10}$, the simulation results indicate that the reflected waves can be affected significantly by the diagonal elements of $\tilde{\alpha}_{ee}$ and $\tilde{\alpha}_{mm}$.

Figures (c) and (d) show that all the entries of $\tilde{\alpha}_{em}$ are of the order of $10^{-26}$. Similar results for $\tilde{\alpha}_{me}$ can be obtained in the same way and are not plotted here. Therefore, we can approximate the polarizability matrix as:

$$
\begin{bmatrix}
\tilde{\alpha}_{ee} & \tilde{\alpha}_{em} \\
\tilde{\alpha}_{me} & \tilde{\alpha}_{mm}
\end{bmatrix}
\approx
\begin{bmatrix}
\tilde{\alpha}_{ee} & 0 \\
0 & \tilde{\alpha}_{mm}
\end{bmatrix}
$$

$$
\tilde{\alpha}_{ee}^{xx} \quad \text{and} \quad \tilde{\alpha}_{ee}^{yy}
$$

$\tilde{\alpha}_{ee}^{xx}$ and $\tilde{\alpha}_{ee}^{yy}$ are compared in Fig. 8 (a). It can be seen that $\tilde{\alpha}_{ee}^{xx}$ and $\tilde{\alpha}_{ee}^{yy}$ is close around 2.8 THz, and are almost purely imaginary. The reflection, transmission, and absorption coefficients for the metasurface in
Fig. 7. The normalized polarizability results of Model 1.

Fig. 8. The normalized polarizabilities and absorption coefficients of Model 1.

Model 1 are plotted in Fig. 8 (b). The subscript 1 or 2 corresponds to the excitation port number as defined in Fig. 6, so it indicates the direction of the incident wave. Maximum absorption coefficient of 92.7% can be seen at 2.79 THz, which agrees with the polarizability results shown in Fig. 8 (a). Since the structure bears both mirror symmetry in the z-direction and rotational symmetry in the xOy plane, the absorber functions identically for incidences from +z and -z directions, and is polarization insensitive.

The normalized polarizabilities $\sim\alpha_{ee}$, $\sim\alpha_{em}$, $\sim\alpha_{me}$ and $\sim\alpha_{mm}$ of Model 2 can also be obtained. Similarly to Model 1, the normalized polarizabilities of Model 2 can also be approximated by equation (8).

Comparing $\sim\alpha_{xx}$ plotted in Fig. 9 (a), we can see around 3.5 THz $\sim\alpha_{xx}$ and $\sim\alpha_{mm}$ are close and are almost purely imaginary. Correspondingly, peak absorptions occur around this frequency (Fig. 9 (b)). This metasurface is still polarization insensitive. However, since the structure loses the mirror symmetry in the z-direction, a slight difference in $A_1$ and $A_2$ can be observed, indicating the metasurface functions differently for the upward and the downward incidences.
Fig. 9. The normalized polarizabilities and absorption coefficients of Model 2.

Specifically, the absorption coefficient changes from 92.5% (at 3.52 THz) to 96.7% (at 3.51 THz) when the incident direction changes from -z to +z.

Similar conclusions can be drawn with Model 3. The normalized polarizabilities $\tilde{\alpha}_{ee}$, $\tilde{\alpha}_{em}$, $\tilde{\alpha}_{me}$ and $\tilde{\alpha}_{mm}$ of Model 3 are similar with Model 1, in which polarizabilities can be approximated by equation (8).

$\tilde{\alpha}_{xx}^{ee}$ and $\tilde{\alpha}_{mn}^{mm}$ is close around 4.0 THz, and are almost purely imaginary (Fig. 10 (a)). Accordingly, peak absorption of 93.8% can be found at 3.94 THz (Fig. 10 (b)). Due to its structural symmetry, the absorber in this model is polarization insensitive and bi-directional.

To sum up, the above investigation validates the thermal controlling of the absorbing frequencies, with the overall absorption coefficients of over 90%.

C. Effective circuit analysis

The operation of the proposed temperature controlled absorbers can be understood by equivalent circuit models. In this section, we used the commercial software of Advanced Design System (ADS) to perform the circuit analysis. Through the structure analysis, we can determine the equivalent circuit, as shown in Fig. 11.

Fig. 10. The normalized polarizabilities and absorption coefficients of Model 3.

Fig. 11. Schematic of effective circuits. (a) Model 1, (b) Model 2, and (c) Model 3.
whose parameters can be further approximated through optimization.

The equivalent circuit models for Models 1 to 3 are plotted in Fig. 11. Due to the z-directional symmetry in the physical structures, models in Figs. 11 (a) and (c) demonstrate corresponding port symmetry. \( \eta_0 \) stands for the wave impedance in free space. The parameters are summarized in Table 2.

Table 2: Parameters of the equivalent circuit models

<table>
<thead>
<tr>
<th>Model</th>
<th>a</th>
<th>b</th>
<th>c</th>
</tr>
</thead>
<tbody>
<tr>
<td>L1 (pH)</td>
<td>1.05</td>
<td>1.05</td>
<td>1.05</td>
</tr>
<tr>
<td>L2 (pH)</td>
<td>0.002</td>
<td>0.002</td>
<td>0.002</td>
</tr>
<tr>
<td>L3 (pH)</td>
<td>1.93</td>
<td>1.93</td>
<td>1.93</td>
</tr>
<tr>
<td>L4 (pH)</td>
<td>-</td>
<td>0.42</td>
<td>0.42</td>
</tr>
<tr>
<td>C1 (pF)</td>
<td>0.003</td>
<td>0.003</td>
<td>0.003</td>
</tr>
<tr>
<td>C2 (pF)</td>
<td>0.0003</td>
<td>0.0003</td>
<td>0.0003</td>
</tr>
<tr>
<td>C3 (pF)</td>
<td>8.42</td>
<td>8.42</td>
<td>8.42</td>
</tr>
<tr>
<td>C4 (pF)</td>
<td>-</td>
<td>0.002</td>
<td>0.002</td>
</tr>
<tr>
<td>R1 (Ω)</td>
<td>377</td>
<td>377</td>
<td>377</td>
</tr>
<tr>
<td>R2 (Ω)</td>
<td>17</td>
<td>17</td>
<td>17</td>
</tr>
<tr>
<td>R3 (Ω)</td>
<td>1288.7</td>
<td>1288.7</td>
<td>1288.7</td>
</tr>
</tbody>
</table>

The simulation results of HFSS and ADS for the three models are compared in Fig. 12. As in Figs. 8–10, the subscript indicates the port of excitation. It can be seen that the ADS and HFSS simulation results agree well at the absorption frequencies for all the models, which validates the effective circuit models. We can also see that the HFSS models have broader absorption frequency bands than the ADS models. The reason is that the circuit models have fewer degrees of freedom, leading to stronger sensitivity to frequency. If a more complex circuit model design could be adopted, the results, it would be suggested, would be more consistent.

V. CONCLUSION

In this study, we analyzed the stability of an \( \Omega \)-shaped absorber and designed two temperature-controlled EM absorbers based on electromagnetism-thermodynamics-structural mechanics multiphysics simulation. Up to the temperature of 1761.4 K, which is close to the melting temperature of the material, the expansion of the \( \Omega \)-shaped inclusion is within the order of 0.1 \( \mu \)m with expansion rate of no greater than 2.58%. The absorption coefficient maintained at 92.7% at 2.79 THz. This demonstrated the thermal stability of the \( \Omega \) absorber both in structure and in EM wave absorption function. By adding thermistors, two temperature-controlled absorbers were designed. When the temperature rises, the simulated absorption of the two proposed absorbers demonstrated a frequency shift from 2.79 THz to 3.51 (+0.01) THz and 3.94 THz, with corresponding absorption coefficients of 92.5 (+4.2)%.
and 93.8%, respectively. At the end of the paper, the effective circuit model method is used to analyze the two metasurface absorbers. In the THz frequency regime, the proposed thermal-controlled absorbers have substantial potential for being used for spatial light modulators, sensors, and bolometers.

REFERENCES


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